



## 6-Pin DIP Optoisolators Transistor Output

The 4N35, 4N36 and 4N37 devices consist of a gallium arsenide infrared emitting diode optically coupled to a monolithic silicon phototransistor detector.

- Current Transfer Ratio — 100% Minimum @ Specified Conditions
- Guaranteed Switching Speeds
- Meets or Exceeds all JEDEC Registered Specifications
- *To order devices that are tested and marked per VDE 0884 requirements, the suffix "V" must be included at end of part number. VDE 0884 is a test option.*

### Applications

- General Purpose Switching Circuits
- Interfacing and coupling systems of different potentials and impedances
- Regulation Feedback Circuits
- Monitor & Detection Circuits
- Solid State Relays

### MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
<b>INPUT LED</b>			
Reverse Voltage	$V_R$	6	Volts
Forward Current — Continuous	$I_F$	60	mA
LED Power Dissipation @ $T_A = 25^\circ\text{C}$ with Negligible Power in Output Detector Derate above $25^\circ\text{C}$	$P_D$	120 1.41	mW mW/ $^\circ\text{C}$
<b>OUTPUT TRANSISTOR</b>			
Collector-Emitter Voltage	$V_{CEO}$	30	Volts
Emitter-Base Voltage	$V_{EBO}$	7	Volts
Collector-Base Voltage	$V_{CBO}$	70	Volts
Collector Current — Continuous	$I_C$	150	mA
Detector Power Dissipation @ $T_A = 25^\circ\text{C}$ with Negligible Power in Input LED Derate above $25^\circ\text{C}$	$P_D$	150 1.76	mW mW/ $^\circ\text{C}$

### TOTAL DEVICE

Isolation Source Voltage(1) (Peak ac Voltage, 60 Hz, 1 sec Duration)	$V_{ISO}$	7500	Vac(pk)
Total Device Power Dissipation @ $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	250 2.94	mW mW/ $^\circ\text{C}$
Ambient Operating Temperature Range(2)	$T_A$	-55 to +100	$^\circ\text{C}$
Storage Temperature Range(2)	$T_{Stg}$	-55 to +150	$^\circ\text{C}$
Soldering Temperature (10 sec, 1/16" from case)	$T_L$	260	$^\circ\text{C}$

1. Isolation surge voltage is an internal device dielectric breakdown rating.  
For this test, Pins 1 and 2 are common, and Pins 4, 5 and 6 are common.
2. Refer to Quality and Reliability Section in Opto Data Book for information on test conditions.

Preferred devices are Motorola recommended choices for future use and best overall value.

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**4N35\***

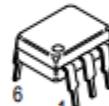
**4N36**

**4N37**

[CTR = 100% Min]

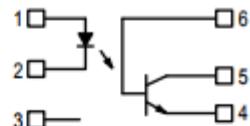
\*Motorola Preferred Device

### STYLE 1 PLASTIC



STANDARD THRU HOLE  
CASE 730A-04

### SCHEMATIC



- PIN 1. LED ANODE  
2. LED CATHODE  
3. N.C.  
4. Emitter  
5. Collector  
6. Base

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)<sup>(1)</sup>

Characteristic	Symbol	Min	Typ <sup>(1)</sup>	Max	Unit
<b>INPUT LED</b>					
Forward Voltage ( $I_F = 10 \text{ mA}$ ) $T_A = 25^\circ\text{C}$ $T_A = -55^\circ\text{C}$ $T_A = 100^\circ\text{C}$	$V_F$	0.8 0.9 0.7	1.15 1.3 1.05	1.5 1.7 1.4	V
Reverse Leakage Current ( $V_R = 6 \text{ V}$ )	$I_R$	—	—	10	$\mu\text{A}$
Capacitance ( $V = 0 \text{ V}$ , $f = 1 \text{ MHz}$ )	$C_J$	—	18	—	pF
<b>OUTPUT TRANSISTOR</b>					
Collector-Emitter Dark Current ( $V_{CE} = 10 \text{ V}$ , $T_A = 25^\circ\text{C}$ ) ( $V_{CE} = 30 \text{ V}$ , $T_A = 100^\circ\text{C}$ )	$I_{CEO}$	—	1 —	50 500	nA $\mu\text{A}$
Collector-Base Dark Current ( $V_{CB} = 10 \text{ V}$ ) $T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$	$I_{CBO}$	—	0.2 100	20 —	nA
Collector-Emitter Breakdown Voltage ( $I_C = 1 \text{ mA}$ )	$V_{(BR)CEO}$	30	45	—	V
Collector-Base Breakdown Voltage ( $I_C = 100 \mu\text{A}$ )	$V_{(BR)CBO}$	70	100	—	V
Emitter-Base Breakdown Voltage ( $I_E = 100 \mu\text{A}$ )	$V_{(BR)EBO}$	7	7.8	—	V
DC Current Gain ( $I_C = 2 \text{ mA}$ , $V_{CE} = 5 \text{ V}$ )	$h_{FE}$	—	400	—	—
Collector-Emitter Capacitance ( $f = 1 \text{ MHz}$ , $V_{CE} = 0$ )	$C_{CE}$	—	7	—	pF
Collector-Base Capacitance ( $f = 1 \text{ MHz}$ , $V_{CB} = 0$ )	$C_{CB}$	—	19	—	pF
Emitter-Base Capacitance ( $f = 1 \text{ MHz}$ , $V_{EB} = 0$ )	$C_{EB}$	—	9	—	pF
<b>COUPLED</b>					
Output Collector Current ( $I_F = 10 \text{ mA}$ , $V_{CE} = 10 \text{ V}$ ) $T_A = 25^\circ\text{C}$ $T_A = -55^\circ\text{C}$ $T_A = 100^\circ\text{C}$	$I_C$ (CTR) <sup>(2)</sup>	10 (100) 4 (40) 4 (40)	30 (300) — —	— — —	mA (%)
Collector-Emitter Saturation Voltage ( $I_C = 0.5 \text{ mA}$ , $I_F = 10 \text{ mA}$ )	$V_{CE(\text{sat})}$	—	0.14	0.3	V
Turn-On Time	$(I_C = 2 \text{ mA}, V_{CC} = 10 \text{ V}, R_L = 100 \Omega)$ <sup>(3)</sup>	$t_{on}$	—	7.5	$\mu\text{s}$
Turn-Off Time		$t_{off}$	—	5.7	$\mu\text{s}$
Rise Time		$t_r$	—	3.2	$\mu\text{s}$
Fall Time		$t_f$	—	4.7	$\mu\text{s}$
Isolation Voltage ( $f = 60 \text{ Hz}$ , $t = 1 \text{ sec}$ )	$V_{ISO}$	7500	—	—	Vac(pk)
Isolation Current <sup>(4)</sup> ( $V_{I-O} = 3550 \text{ Vpk}$ ) ( $V_{I-O} = 2500 \text{ Vpk}$ ) ( $V_{I-O} = 1500 \text{ Vpk}$ )	4N35 4N36 4N37	$I_{ISO}$	— — —	100 100 8	$\mu\text{A}$
Isolation Resistance ( $V = 500 \text{ V}$ ) <sup>(4)</sup>		$R_{ISO}$	10 <sup>11</sup>	—	$\Omega$
Isolation Capacitance ( $V = 0 \text{ V}$ , $f = 1 \text{ MHz}$ ) <sup>(4)</sup>		$C_{ISO}$	—	0.2 2	pF

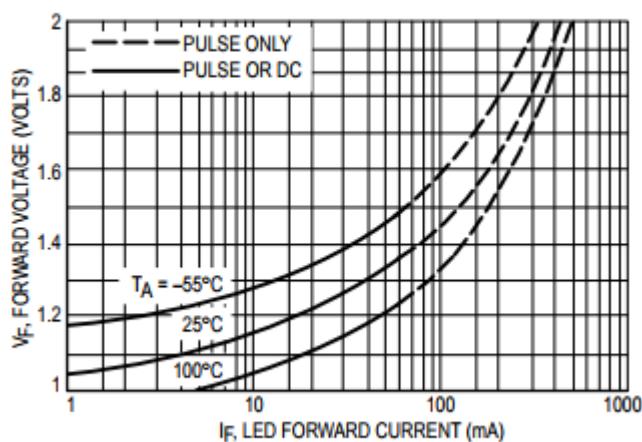
1. Always design to the specified minimum/maximum electrical limits (where applicable).

2. Current Transfer Ratio (CTR) =  $I_C/I_F \times 100\%$ .

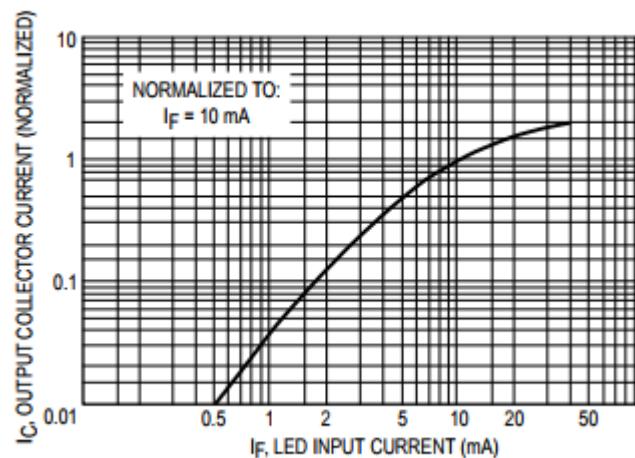
3. For test circuit setup and waveforms, refer to Figure 11.

4. For this test, Pins 1 and 2 are common, and Pins 4, 5 and 6 are common.

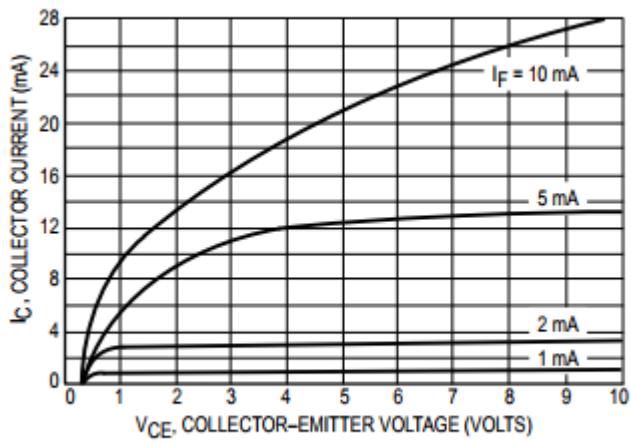
## TYPICAL CHARACTERISTICS



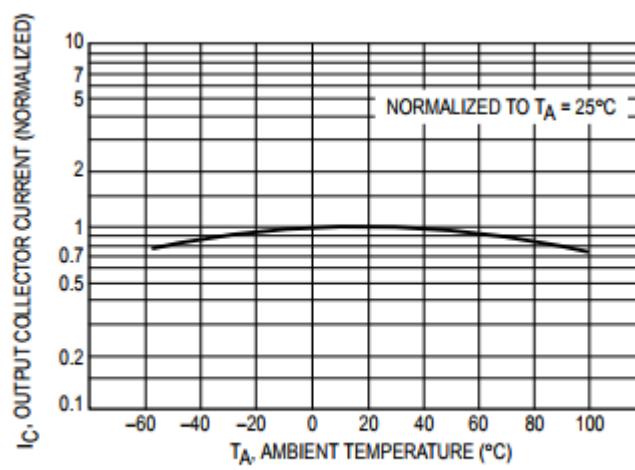
**Figure 1. LED Forward Voltage versus Forward Current**



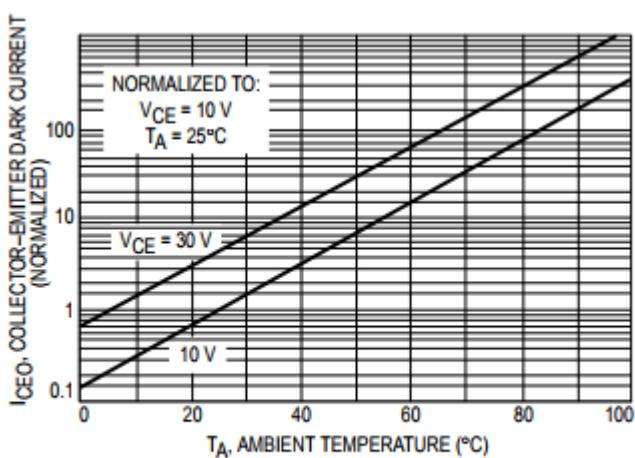
**Figure 2. Output Current versus Input Current**



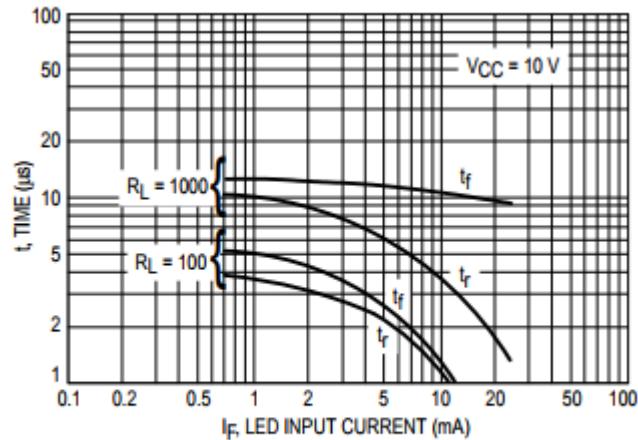
**Figure 3. Collector Current versus Collector-Emitter Voltage**



**Figure 4. Output Current versus Ambient Temperature**



**Figure 5. Dark Current versus Ambient Temperature**



**Figure 6. Rise and Fall Times  
(Typical Values)**

## 4N35 4N36 4N37

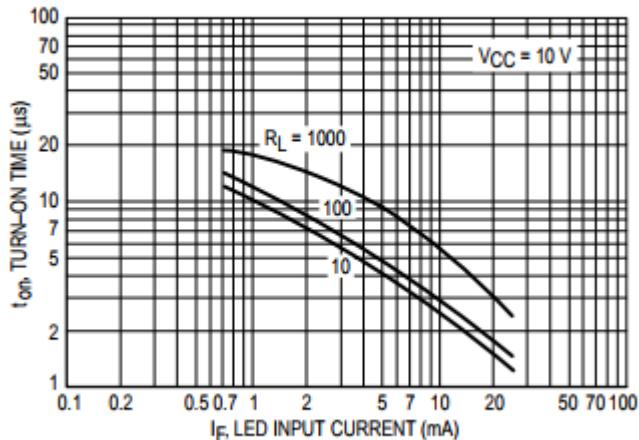


Figure 7. Turn-On Switching Times

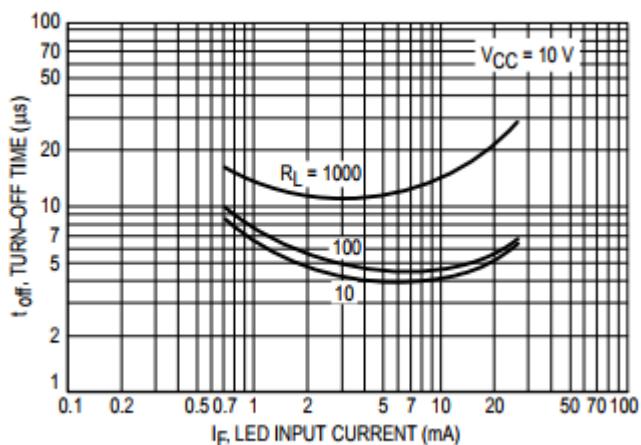


Figure 8. Turn-Off Switching Times

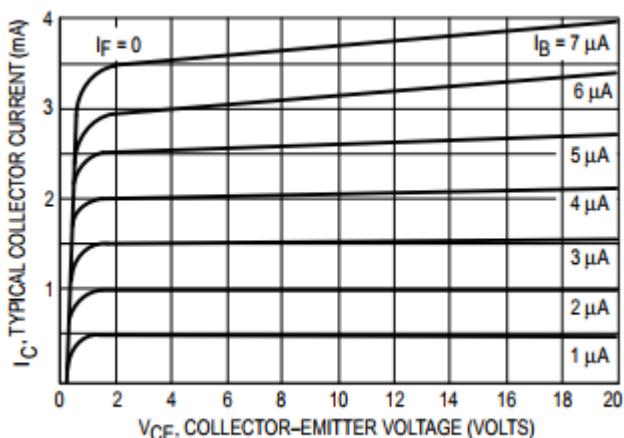


Figure 9. DC Current Gain (Detector Only)

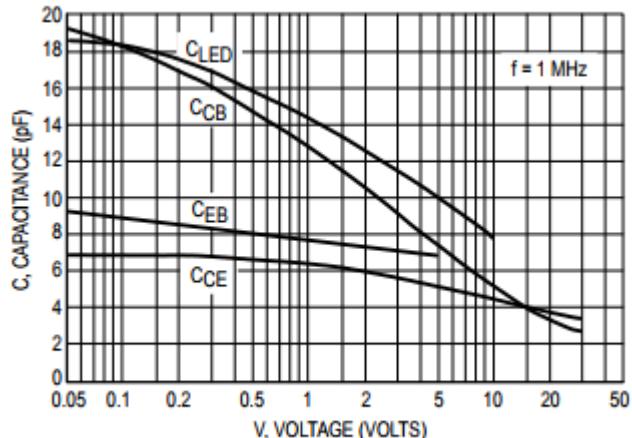


Figure 10. Capacitances versus Voltage

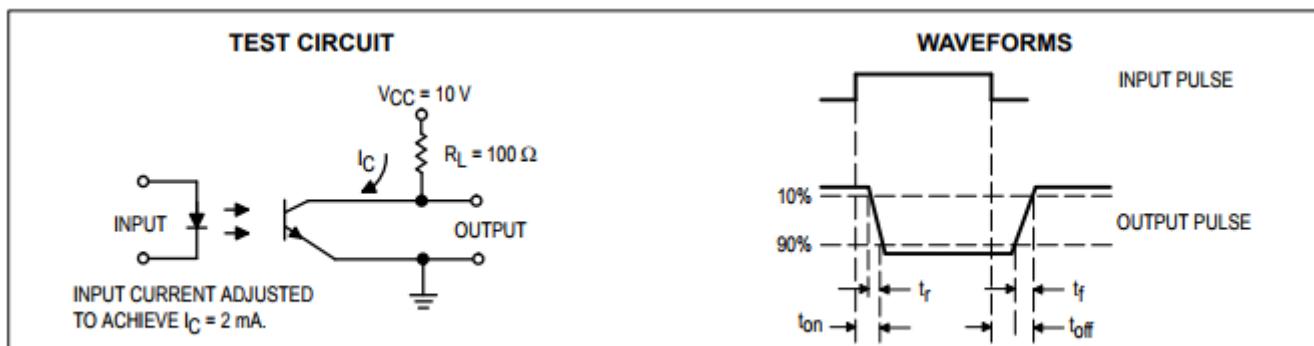


Figure 11. Switching Time Test Circuit and Waveforms